

L Number	Hits	Search Text	DB	Time stamp
1	2	("5480829").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 10:24
2	20	("3684930" "4188710" "4313971" "4540446" "4712291" "4729000" "4746627" "4814851" "4830980" "4833042" "4989065" "4998158" "5045502" "5060031" "5091338" "5093280" "5100835" "5116774" "5144410" "5275971").PN.	USPAT	2004/09/17 10:05
3	4	("3914785" "4001056" "4188710" "4632713").PN.	USPAT	2004/09/17 10:12
4	7	("4471366" "4652896" "4729000" "4771324" "4814851" "4862228" "4899201").PN.	USPAT	2004/09/17 10:16
5	8	("3577286" "3716407" "3753804" "3846169" "3914785" "3923975" "4119994" "4128733").PN.	USPAT	2004/09/17 10:19
6	7387	257/76-78,183-201.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 10:27
7	2109	257/76-78,183-201.ccls. and heterojunction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:08
8	386	(257/76-78,183-201.ccls. and heterojunction) and (selenium Se tellurium Te)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01
9	1	(257/76-78,183-201.ccls. and heterojunction) and ((carrier near supply) with (selenium Se tellurium Te))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:02
10	15	((257/76-78,183-201.ccls. and heterojunction) and (selenium Se tellurium Te)) and (carrier near supply)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:23
11	354956	257/\$.ccls. 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01
12	6070	(257/\$.ccls. 438/\$.ccls.) and heterojunction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:01
13	1250	((257/\$.ccls. 438/\$.ccls.) and heterojunction) and (selenium Se tellurium Te)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:10
14	1	((257/\$.ccls. 438/\$.ccls.) and heterojunction) and ((carrier near supply) with (selenium Se tellurium Te))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:08

15	1	((257/\$.ccls. 438/\$.ccls.) and heterojunction) and (selenium Se tellurium Te)) and ((carrier near supply) near5 between near5 (source darin))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:10
16	2	((257/\$.ccls. 438/\$.ccls.) and heterojunction) and (selenium Se tellurium Te)) and ((carrier near supply) with between with (source darin))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:05
17	9	((257/\$.ccls. 438/\$.ccls.) and heterojunction) and ((carrier near supply) with between with (source darin))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:05
18	13190	heterojunction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:08
19	3	heterojunction and ((carrier near supply) with (selenium Se tellurium Te))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:09
20	2018	heterojunction and (selenium Se tellurium Te)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:10
21	0	(heterojunction and (selenium Se tellurium Te)) and ((carrier near supply) near5 between near5 ((source drain) near (region\$1 area\$1)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:11
22	2	(heterojunction and (selenium Se tellurium Te)) and ((carrier near supply) with between with ((source drain) near (region\$1 area\$1)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:19
23	3	(heterojunction and (selenium Se tellurium Te)) and ((carrier near supply) with between with (source drain))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:13
24	12	heterojunction and ((carrier near supply) with between with (source drain))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:13
25	8	((carrier near supply) with between with ((source drain) near (region\$1 area\$1)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:22
26	19	((carrier near supply) same between same ((source drain) near (region\$1 area\$1)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:20

27	499	((active near (layer film)) with between with ((source drain) near (region\$1 area\$1)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:22
28	4	((active near (layer film)) with between with ((source drain) near (region\$1 area\$1))) and (carrier near supply)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:25
29	19	((active near (layer film)) with between with ((source drain) near (region\$1 area\$1))) and heterojunction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/17 11:26